NSN 5961-00-773-2412

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Inclosure Material:

Metal

Overall Length:

Between 0.305 inches and 0.335 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Mounting hardware and hermetically sealed case

Overall Width Across Flats:

0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to emitter voltage/static/base open and 150.0 collector to base voltage/static/emitter open and 6.0 emitter to base voltage, static, collector open

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Test Data Document:

97942-576r994 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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